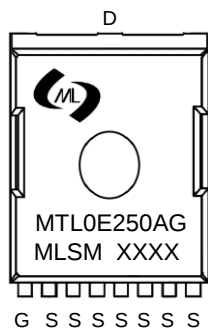


Features

- High Speed Power Switching, Logic level
- Enhanced Body diode DV/DT capability
- Enhanced Avalanche Ruggedness
- 100% UIS Tested, 100% Rg Tested
- Lead Free, Halogen Free

Application

- DC/DC Converter
- Motor Drivers
- Ideal for high-frequency switching and synchronous rectification

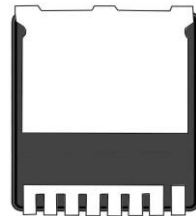


MTL0E250AG: Device code
XXXX: Code

Marking and pin assignment

Product Summary

V_{DS}	$R_{DS(ON)}$ TYP	I_D
40V	1.2m Ω @10V	250A
	1.6m Ω @4.5V	



TOLL-8L view



Schematic diagram



Pb-Free



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
Common Ratings (TC=25°C Unless Otherwise Noted)			
V_{DS}	Drain-Source Breakdown Voltage	40	V
V_{GS}	Gate-Source Voltage	± 20	V
E_{AS}	Single pulse avalanche energy	676	mJ
T_J, T_{STG}	Storage Temperature Range	-55 to 150	°C
I_S	Diode Continuous Forward Current	$T_C=25^\circ\text{C}$ 250	A

Mounted on Large Heat Sink

I_{DM}	Pulse Drain Current Tested	$T_C=25^\circ\text{C}$ 1000	A
I_D	Continuous Drain Current	$T_C=25^\circ\text{C}$ 250	A
P_D	Maximum Power Dissipation	$T_C=25^\circ\text{C}$ 300	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient	55	°C/W

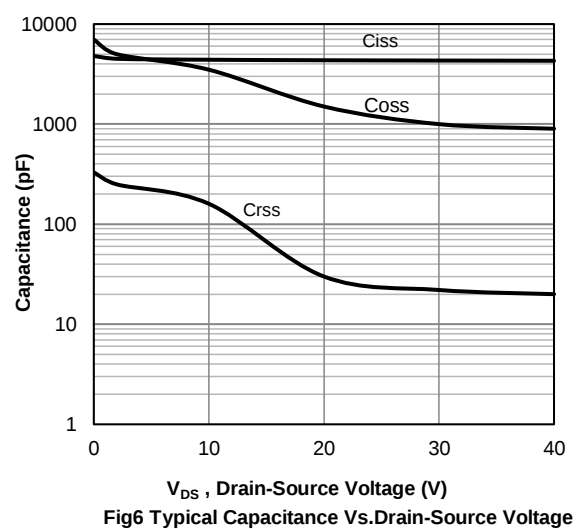
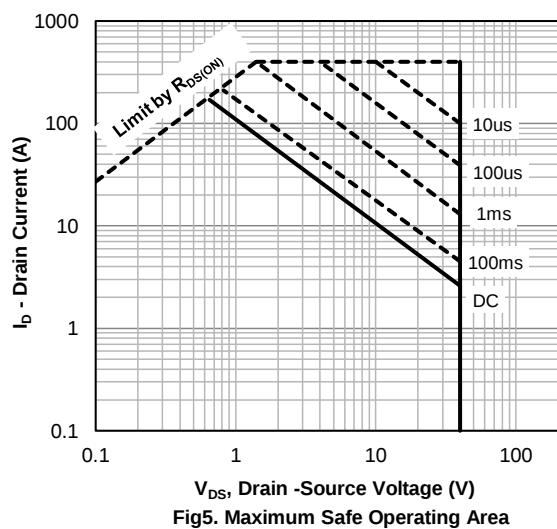
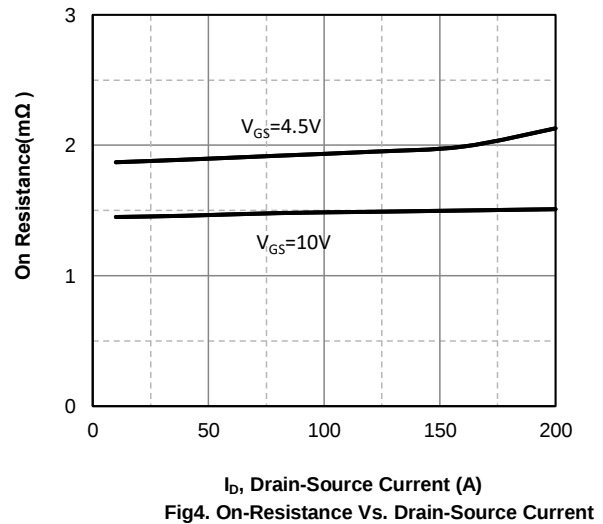
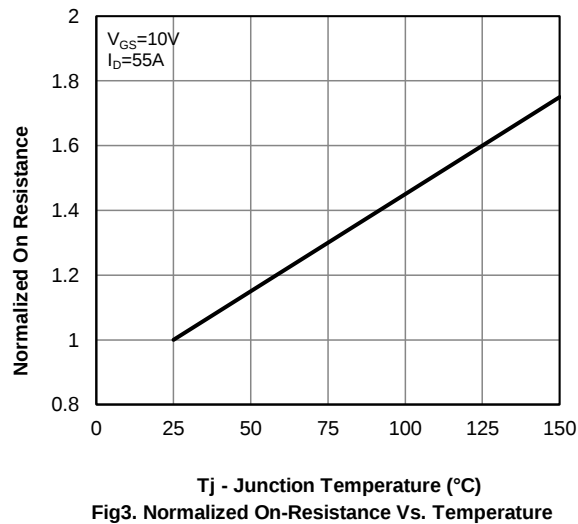
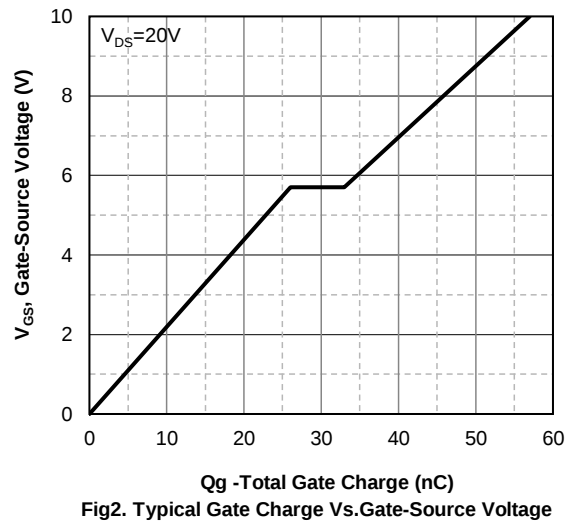
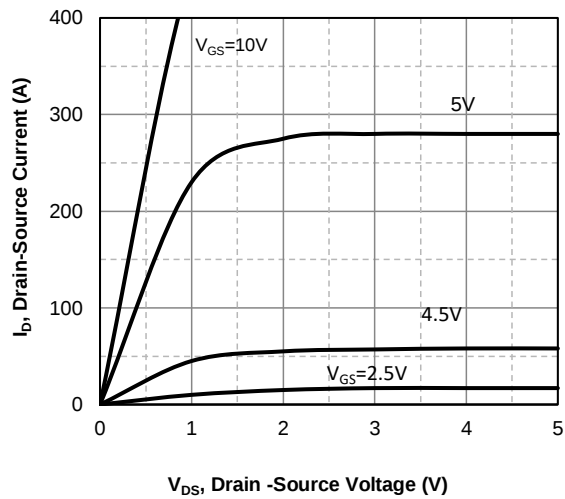
Ordering Information (Example)

Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MTL0E250AG	TOLL-8L	MTL0E250AG	2,000	2,000	14,000	13" reel

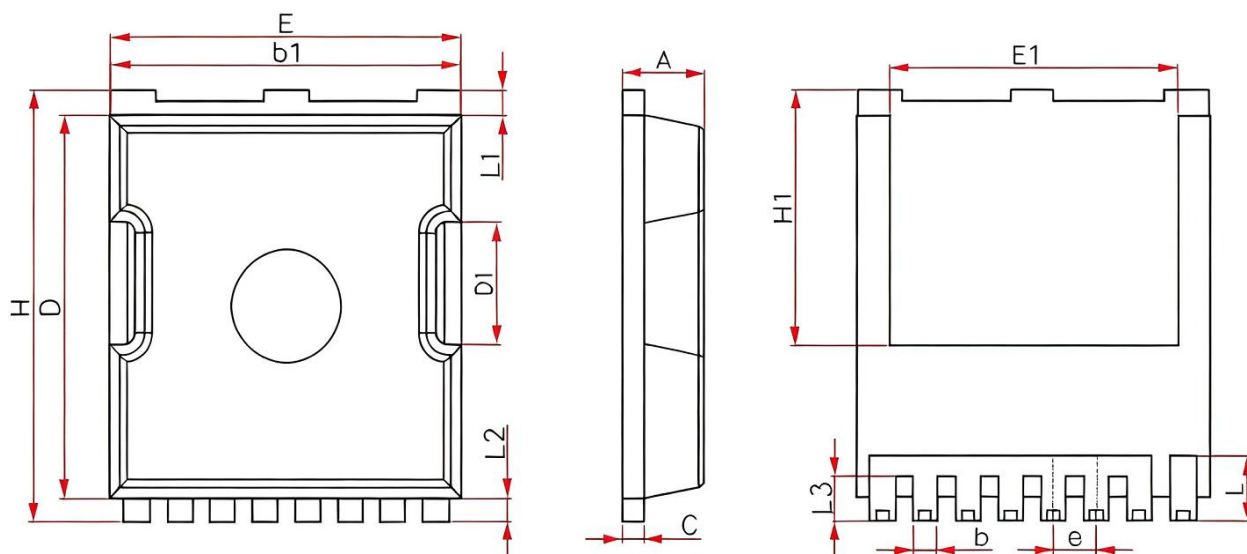
Electrical Characteristics (T_J=25°C unless otherwise noted)

Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
BV(BR)DSS	Drain-Source Breakdown Voltage	VGS=0V, ID=250μA	40	--	--	V
IDSS	Zero Gate Voltage Drain Current	VDS=40V, VGS=0V	--	--	1.0	μA
IGSS	Gate-Body Leakage Current	VGS=±20V, VDS=0V	--	--	±100	nA
VGS(th)	Gate Threshold Voltage	VDS=VGS, ID=250μA	1.0	1.8	2.5	V
RDS(on)	Drain-Source On-State Resistance	VGS=10V, ID=30A	--	1.2	1.9	mΩ
		VGS=4.5V, ID=20A	--	1.6	2.5	mΩ
Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
CISS	Input Capacitance	VDS=20V, VGS=0V, f=500KHz	--	4380	--	pF
COSS	Output Capacitance		--	1490	--	pF
CRSS	Reverse Transfer Capacitance		--	30	--	pF
Switching Characteristics						
Qg	Total Gate Charge	VDS=20V, ID=55A, VGS=10V	--	56	--	nC
Qgs	Gate Source Charge		--	27	--	nC
Qgd	Gate Drain Charge		--	5.6	--	nC
tD(on)	Turn-on Delay Time	VDD=20V, ID=55A, VGS=10V, RG=3Ω	--	22	--	nS
tR	Turn-on Rise Time		--	8.5	--	nS
tD(off)	Turn-Off Delay Time		--	44	--	nS
tF	Turn-Off Fall Time		--	51.8	--	nS
Source- Drain Diode Characteristics						
VSD	Forward on voltage	TJ=25°C, IS=30A,	--	0.9	1.2	V

Typical Operating Characteristics



PDFN5X6-8L Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	2.150	2.450	0.085	0.096
b	0.600	0.900	0.024	0.035
b1	9.650	9.950	0.380	0.392
C	0.350	0.650	0.014	0.026
D	10.180	10.700	0.401	0.421
D1	3.150	3.450	0.124	0.136
E	9.700	10.100	0.382	0.398
E1	7.350	8.450	0.289	0.333
e	1.100	1.300	0.043	0.051
H	11.450	11.950	0.451	0.470
H1	6.550	7.500	0.258	0.295
L	1.350	2.100	0.053	0.083
L1	0.600	0.800	0.024	0.031
L2	0.500	0.700	0.020	0.028
L3	1.050	1.300	0.041	0.051